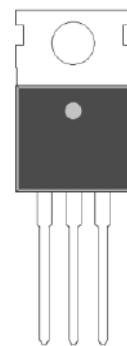


P-Channel Enhancement Mode Power MOSFET

Features:

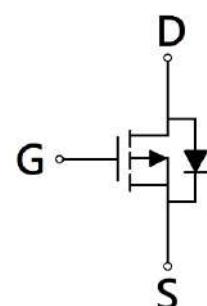
- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic

TO-220



G D S

BV_{DSS}	-60V
$I_D @ V_{GS} = -10V, T_c = 25^\circ C$	-47A
$I_D @ V_{GS} = -10V, T_A = 25^\circ C$	-10A
$R_{DS(ON)} \text{ typ. } @ V_{GS} = -10V, I_D = -10A$	19m Ω



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KE015P06	TO-220 (RoHS compliant)	50 pcs/tube, 20 tubes/box, 5 boxes / carton

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	± 20	
Continuous Drain Current @ V _{GS} =-10V, T _C =25°C	I _D	-47	A
Continuous Drain Current @ V _{GS} =-10V, T _C =100°C		-30	
Continuous Drain Current @ V _{GS} =-10V, T _A =25°C		-10	
Continuous Drain Current @ V _{GS} =-10V, T _A =70°C		-8	
Pulsed Drain Current	I _{DM}	-188	
Continuous Body Diode Forward Current @ T _C =25°C	I _S	-47	
Avalanche Current @ L=0.1mH	I _{AS}	-35	
Avalanche Energy @ L=0.5mH	E _{AS}	100	mJ
Total Power Dissipation	T _C =25°C	*a	W
	T _C =100°C	*a	
	T _A =25°C	*b	
	T _A =70°C	*b	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-case	R _{θJC}	1.3	°C/W
Thermal Resistance, Junction-to-ambient	R _{θJA}	29	

Note:

- *a. The power dissipation P_D is based on T_{J(MAX)}=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
- *b. The value of R_{θJA} is measured with the device mounted on 1 in² FR -4 board with 2 oz. copper, in a still air environment with T_A=25°C. The power dissipation P_D is based on R_{θJA} and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- *c. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and low duty cycles to keep initial T_J=25°C.

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Static						
BV _{DSS}	-60	-	-	V	V _{GS} =0V, I _D =-250μA	
V _{GS(th)}	-2	-	-4		V _{DS} =V _{GS} , I _D =-250μA	
G _{FS}	-	25	-	S	V _{DS} =-10V, I _D =-10A	
I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0V	
I _{DSS}	-	-	-1	μA	V _{DS} =-48V, V _{GS} =0V	
R _{DSS(ON)}	-	19	25	mΩ	V _{GS} =-10V, I _D =-10A	
Dynamic						
C _{iss}	-	2070	-	pF	V _{DS} =-30V, V _{GS} =0V, f=1MHz	
C _{oss}	-	280	-			
C _{rss}	-	120	-			
R _g	-	10	-	Ω	f=1MHz	
Q _g *1, 2	-	36	-	nC	V _{DS} =-30V, I _D =-10A, V _{GS} =-10V	
Q _{gs} *1, 2	-	9	-			
Q _{gd} *1, 2	-	8.7	-			
t _{d(ON)} *1, 2	-	16	-	ns	V _{DS} =-30V, I _D =-10A, V _{GS} =-10V, R _{GS} =1Ω	
t _r *1, 2	-	25	-			
t _{d(OFF)} *1, 2	-	54	-			
t _f *1, 2	-	19	-			
Source-Drain Diode						
V _{SD} *1	-	-0.79	-1.2	V	I _S =-10A, V _{GS} =0V	
t _{rr}	-	18	-	ns	I _F =-10A, dI _F /dt=100A/μs	
Q _{rr}	-	11	-	nC		

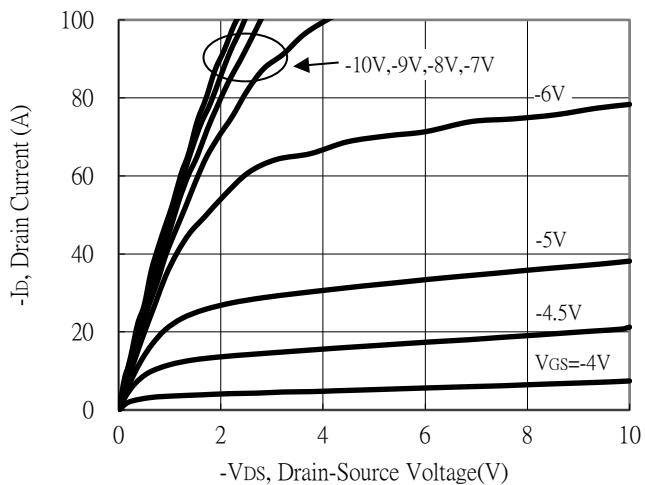
Note:

*1. Pulse Test : Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

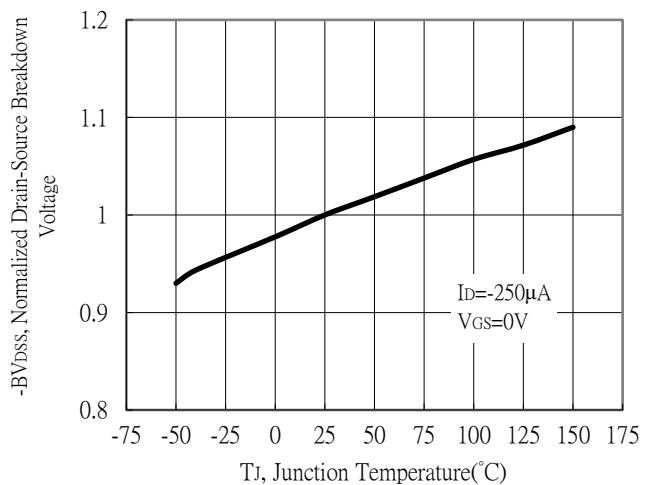
*2. Independent of operating temperature

Typical Characteristics

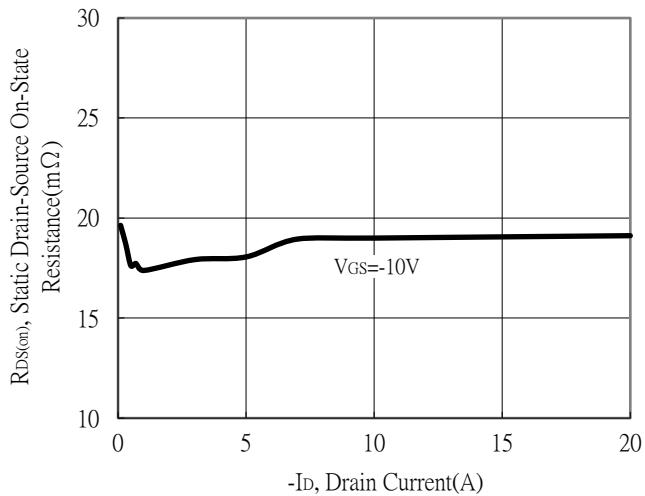
Typical Output Characteristics



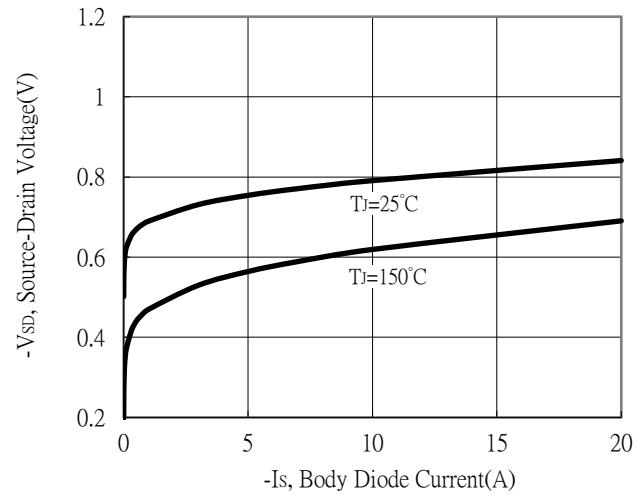
Breakdown Voltage vs Ambient Temperature



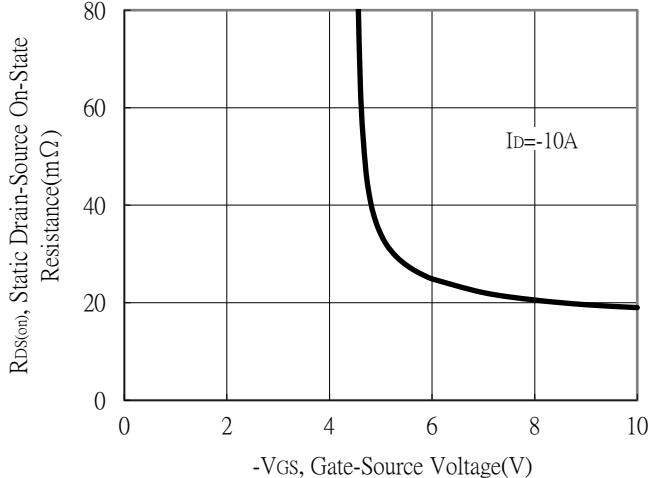
Static Drain-Source On-State resistance vs Drain Current



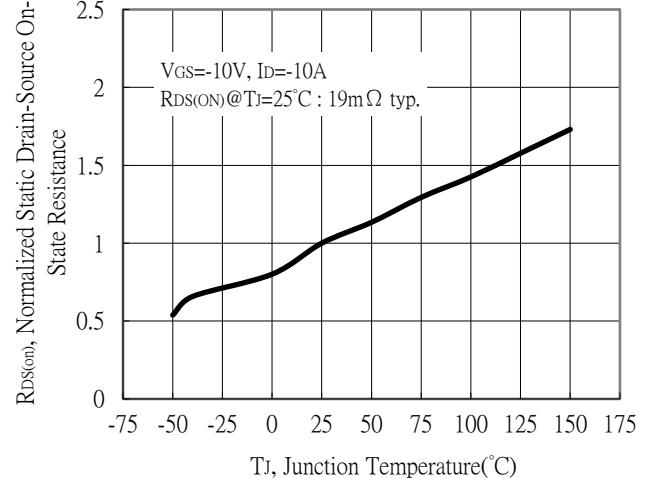
Body Diode Current vs Source-Drain Voltage



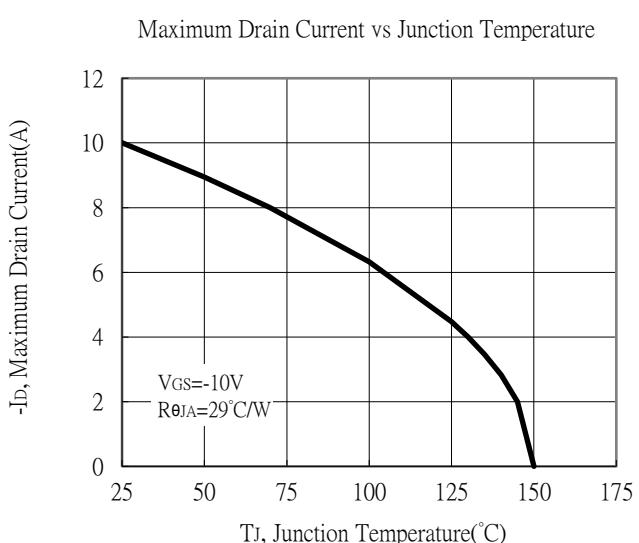
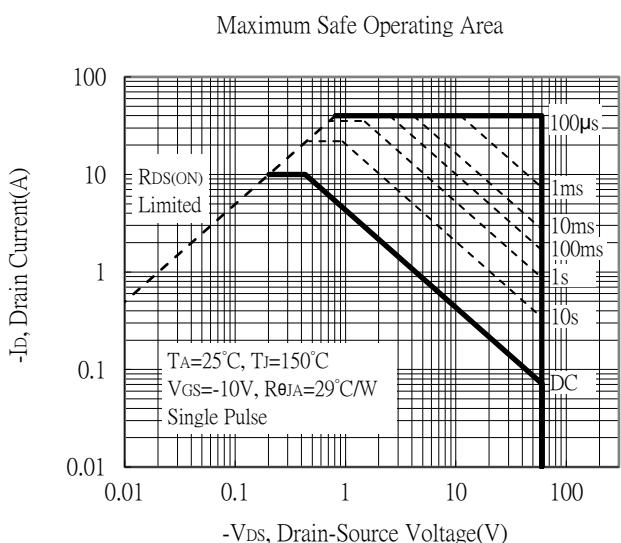
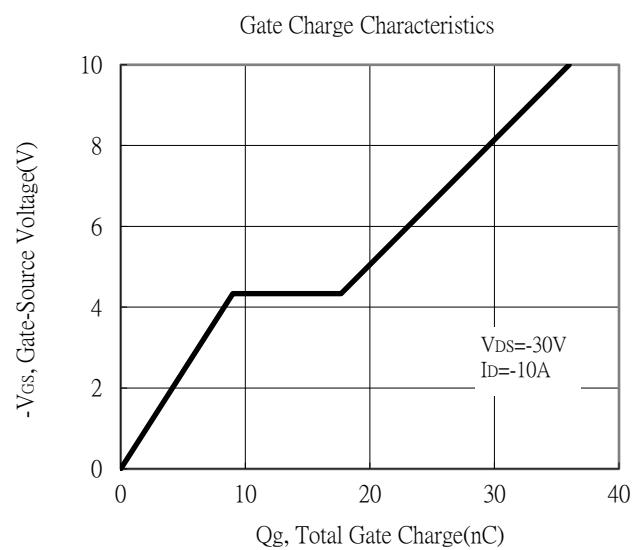
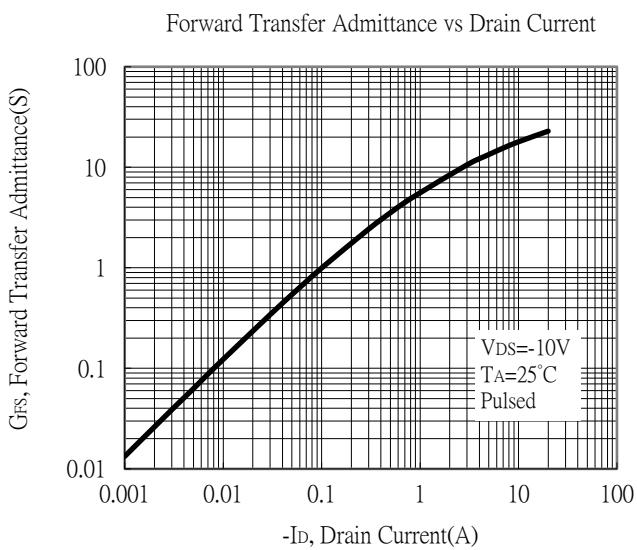
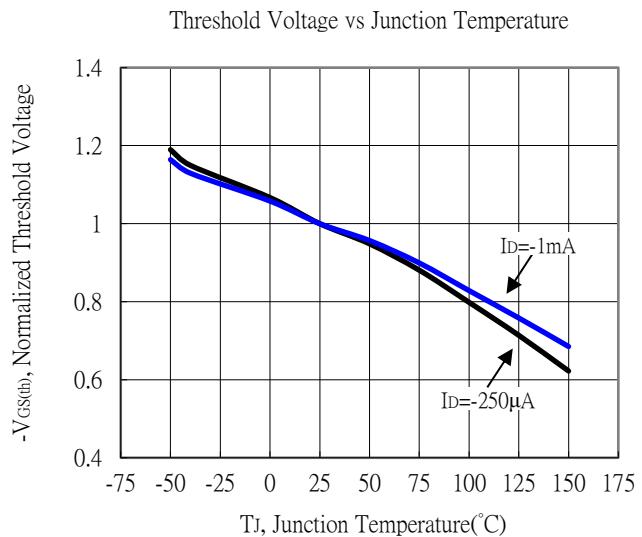
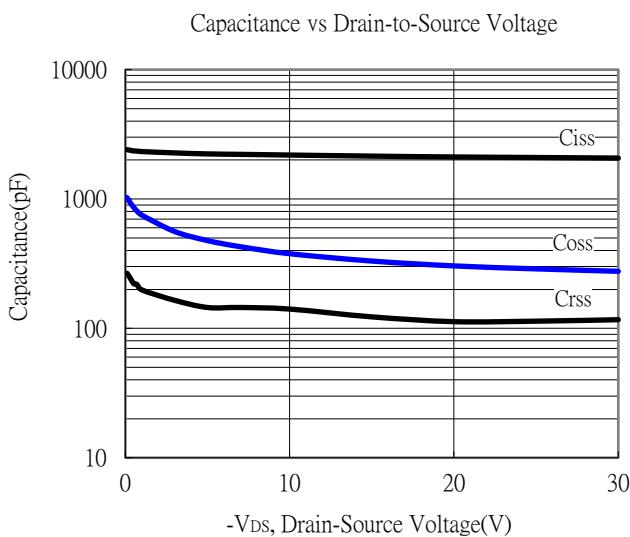
Static Drain-Source On-State Resistance vs Gate-Source Voltage



Drain-Source On-State Resistance vs Junction Temperature

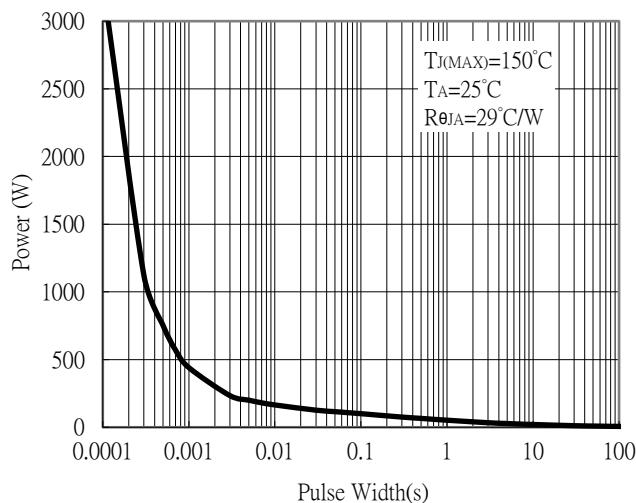


Typical Characteristics (Cont.)

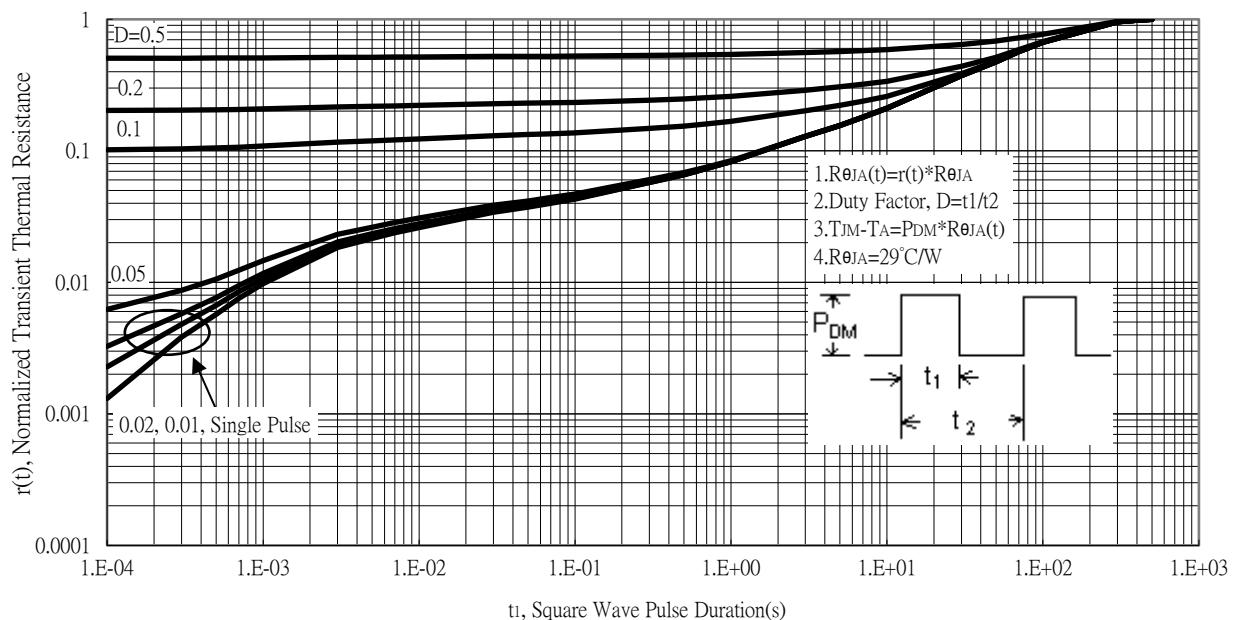


Typical Characteristics (Cont.)

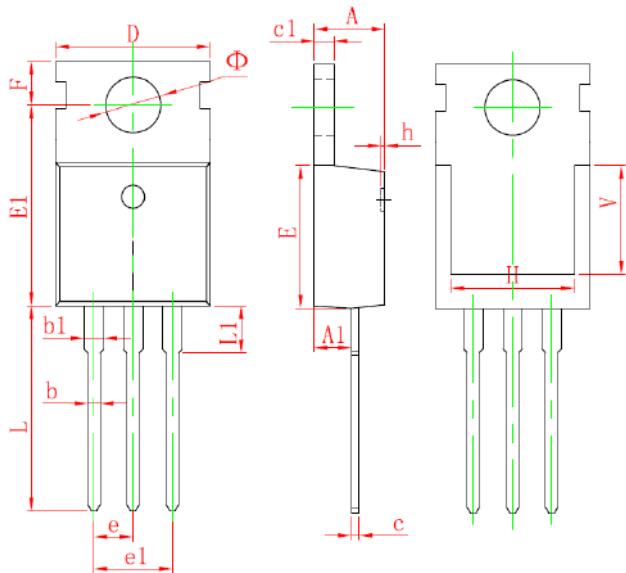
Single Pulse Power Rating, Junction to Ambient



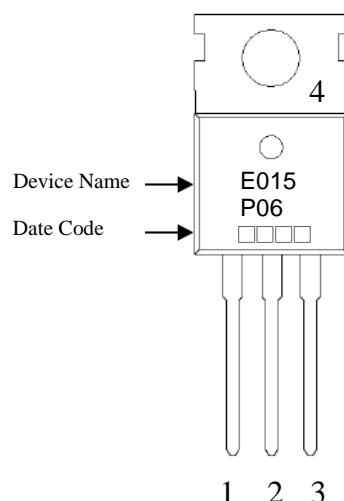
Transient Thermal Response Curves



TO-220 Dimension



Marking:



Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year

2nd code : month code, Jan→A, Feb→B, Mar→C,

Apr→D, May→E, Jun→F, Jul→G, Aug→H,

Sep→J, Oct→K, Nov→L, Dec→M

3rd and 4th codes : production serial number, 01~99

Style: Pin 1.Gate 2.Drain 3.Source
4.Drain

3-Lead TO-220 Plastic Package

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181	e	2.540	TYP	0.100	TYP
A1	2.250	2.550	0.089	0.100	e1	4.980	5.180	0.196	0.204
b	0.710	0.910	0.028	0.036	F	2.650	2.950	0.104	0.116
b1	1.170	1.370	0.046	0.054	H	7.900	8.100	0.311	0.319
c	0.330	0.650	0.013	0.026	h	0.000	0.300	0.000	0.012
c1	1.200	1.400	0.047	0.055	L	12.900	13.400	0.508	0.528
D	9.910	10.250	0.390	0.404	L1	2.850	3.250	0.112	0.128
E	8.950	9.750	0.352	0.384	V	7.500	REF	0.295	REF
E1	12.650	12.950	0.498	0.510	Φ	3.400	3.800	0.134	0.150